

NPN SILICON RF TWIN TRANSISTOR

μ PA828TD

NPN SILICON RF TRANSISTOR (WITH 2 ELEMENTS) IN A 6-PIN LEAD-LESS MINIMOLD (M16, 1208 PKG)

FEATURES

- Built-in low phase distortion transistor suited for OSC applications $f_T = 9.0 \text{ GHz TYP.}$, $\left| S_{21e} \right|^2 = 7.5 \text{ dB TYP.}$ @ VcE = 1 V, Ic = 10 mA, f = 2 GHz NF = 1.3 dB TYP. @ VcE = 1 V, Ic = 3 mA, f = 2 GHz
- Built-in 2 transistors (2 × NE687)
- 6-pin lead-less minimold (M16, 1208 PKG)

BUILT-IN TRANSISTORS

	Q1, Q2
3-pin thin-type ultra super minimold part No.	NE687

<R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
μPA828TD	μPA828TD-A	6-pin lead-less minimold	50 pcs (Non reel)	8 mm wide embossed taping
μPA828TD-T3	μPA828TD-T3-A	(M16, 1208 PKG) (Pb-Free)	10 kpcs/reel	• Pin 1 (Q1 Collector), Pin 6 (Q1 Base) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office. The unit sample quantity is 50 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	5.0	V
Collector to Emitter Voltage	Vceo	3.0	V
Emitter to Base Voltage	VEBO	2	V
Collector Current	lc	30	mA
Total Power Dissipation	Ptot Note	90 in 1 element	mW
		180 in 2 elements	
Junction Temperature	Tj	150	
Storage Temperature	T _{stg}	−65 to +150 °(

Note Mounted on 1.08 $\text{cm}^2 \times 1.0 \text{ mm}$ (t) glass epoxy PCB

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characterstics						
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	_	-	100	nA
Emitter Cut-off Current	ІЕВО	VEB = 1 V, Ic = 0 mA	-	-	100	nA
DC Current Gain	hfe Note 1	VcE = 2 V, Ic = 20 mA	70	-	140	-
RF Characterstics						
Gain Bandwidth Product (1)	f⊤	VcE = 1 V, Ic = 10 mA, f = 2 GHz	7.0	9.0	-	GHz
Gain Bandwidth Product (2)	f⊤	VcE = 2 V, Ic = 20 mA, f = 2 GHz	9.0	11.0	-	GHz
Insertion Power Gain (1)	S _{21e} ²	VcE = 1 V, Ic = 10 mA, f = 2 GHz	6.0	7.5	-	dB
Insertion Power Gain (2)	S _{21e} ²	VcE = 2 V, Ic = 20 mA, f = 2 GHz	7.0	8.5	-	dB
Noise Figure (1)	NF	$V_{CE} = 1 \text{ V}, \text{ Ic} = 3 \text{ mA}, \text{ f} = 2 \text{ GHz},$ $Z_{S} = Z_{opt}$	-	1.3	2.0	dB
Noise Figure (2)	NF	$V_{CE} = 2 \text{ V}, \text{ Ic} = 3 \text{ mA}, \text{ f} = 2 \text{ GHz}, $ $Z_{S} = Z_{opt}$	-	1.3	2.0	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 2 V, IE = 0 mA, f = 1 MHz	-	0.4	0.8	pF
h _{FE} Ratio	hfe1/hfe2	VcE = 2 V, Ic = 20 mA, hre1: Smaller value of Q1 and Q2, hre2: Larger value of Q1 and Q2	0.85	_	_	_

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

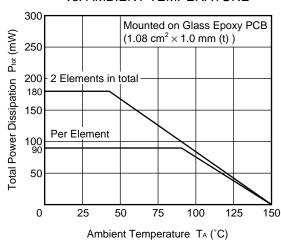
2. Collector to base capacitance when the emitter grounded.

hfe CLASSIFICATION

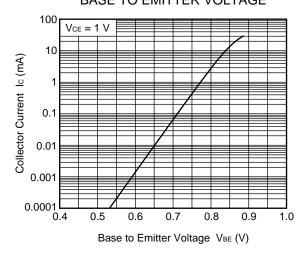
Rank	FB		
Marking	kL		
h _{FE} Value	70 to 140		

<R> TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

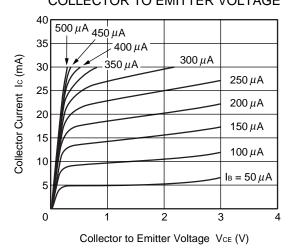
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

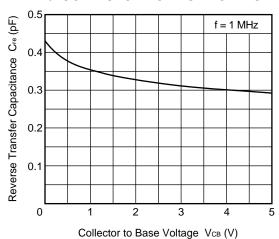


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

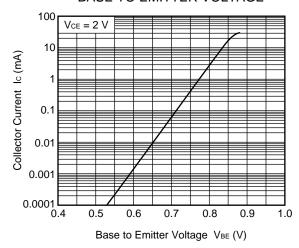


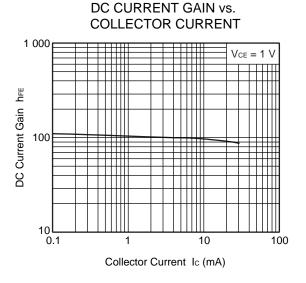
Remark The graphs indicate nominal characteristics.

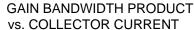
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

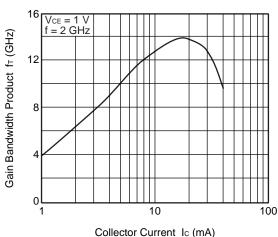


COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

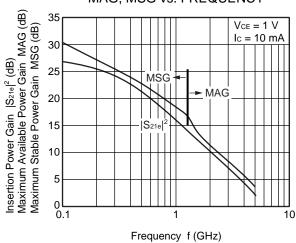






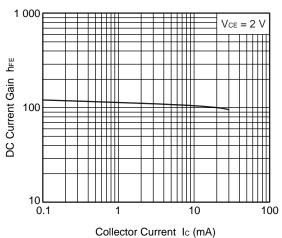


INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY

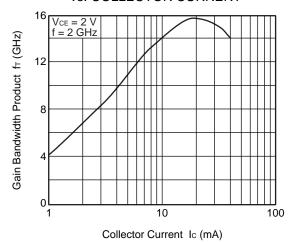


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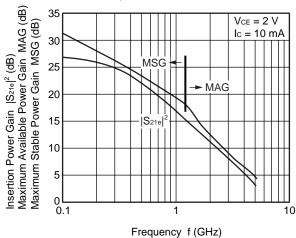
DC CURRENT GAIN vs. COLLECTOR CURRENT

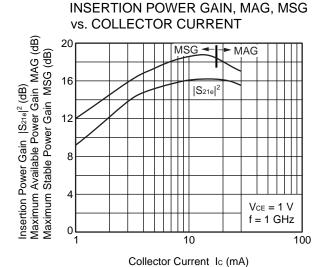


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

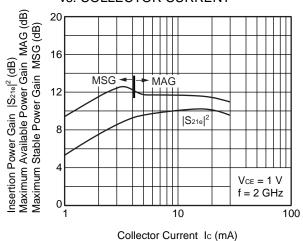


INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY

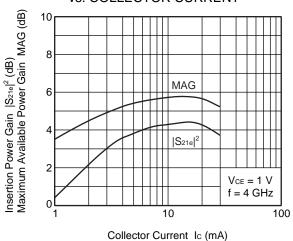




INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

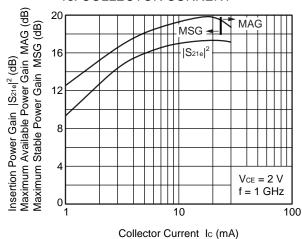


INSERTION POWER GAIN, MAG vs. COLLECTOR CURRENT

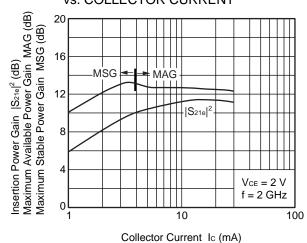


Remark The graphs indicate nominal characteristics.

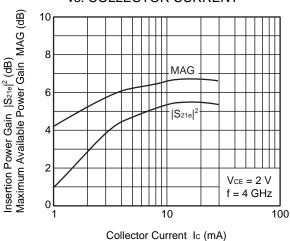
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

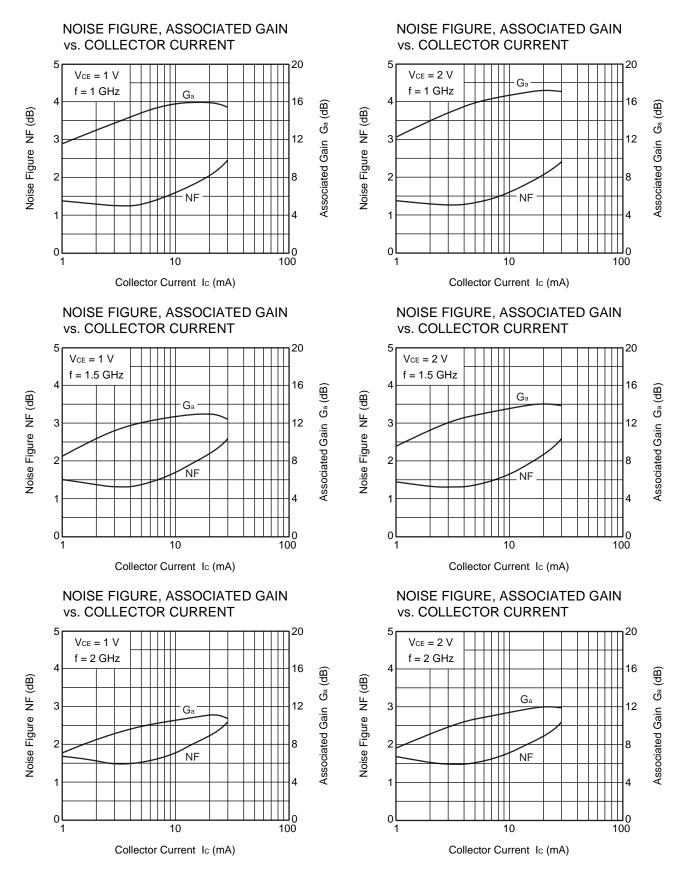


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG vs. COLLECTOR CURRENT

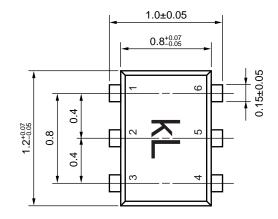


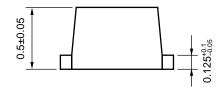


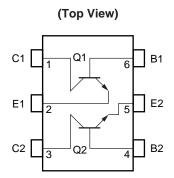
Remark The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (M16, 1208 PKG) (UNIT: mm)







PIN CONNECTIONS

- 1. Collector (Q1)
- 2. Emitter (Q1)
- 3. Collector (Q2)
- 4. Base (Q2)
- 5. Emitter (Q2)
- 6. Base (Q1)

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